

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SA1314

Strobe Flash Applications
 Audio Power Applications

- High DC current gain and excellent linearity
 : $h_{FE(1)} = 140$ to 600 ($V_{CE} = -1$ V, $I_C = -0.5$ A)
 : $h_{FE(2)} = 60$ (min), 120 (typ.), ($V_{CE} = -1$ V, $I_C = -4$ A)
- Low saturation voltage
 : $V_{CE(sat)} = -0.5$ V (max) ($I_C = -2$ A, $I_B = -50$ mA)
- Small package
- Complementary to 2SC2982

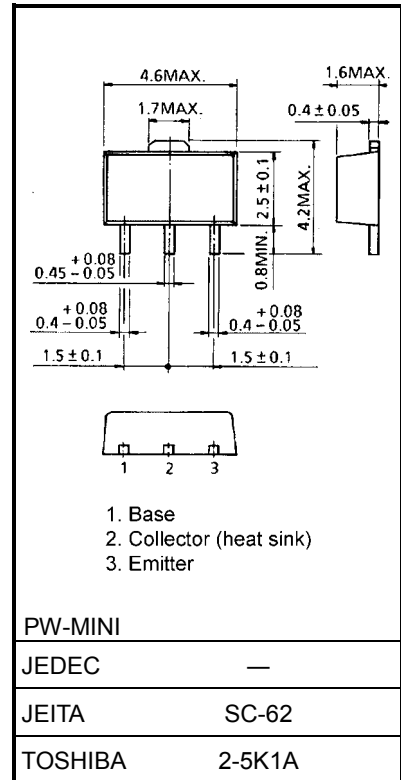
Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	-20	V
Collector-emitter voltage		V_{CEO}	-10	V
Emitter-base voltage		V_{EBO}	-6	V
Collector current	DC	I_C	-2	A
	Pulsed (Note 1)	I_{CP}	-4	
Base current		I_B	-2	A
Collector power dissipation		P_C	500	mW
		P_C (Note 2)	1000	
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-55 to 150	°C

Note 1: Pulse test: pulse width = 10 mS (max), duty cycle = 30% (max)

Note 2: Mounted on ceramic substrate (250 mm² × 0.8 t)

Unit: mm



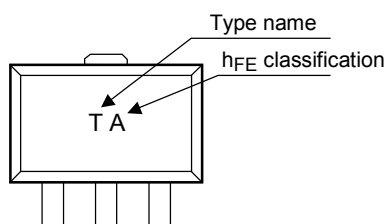
Weight: 0.05 g (typ.)

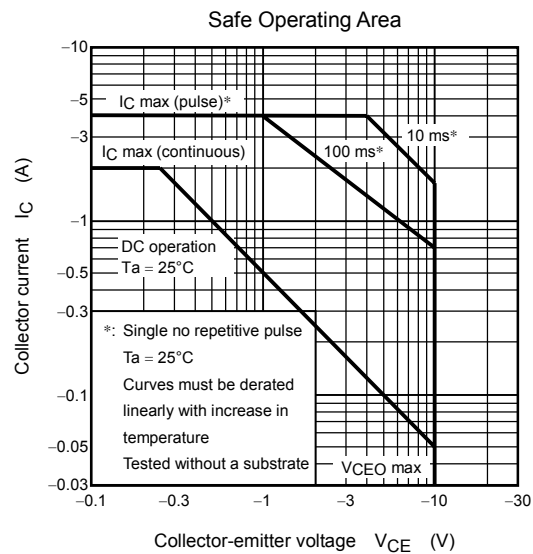
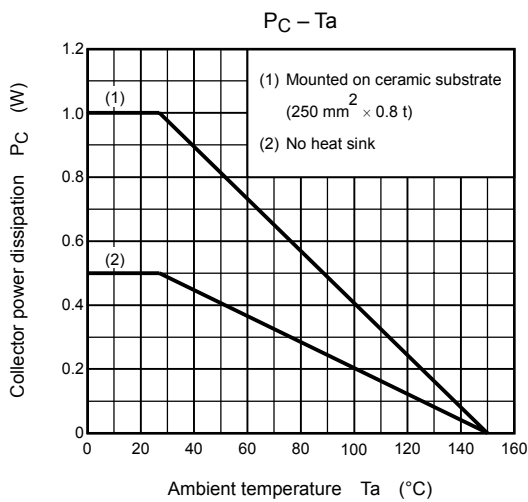
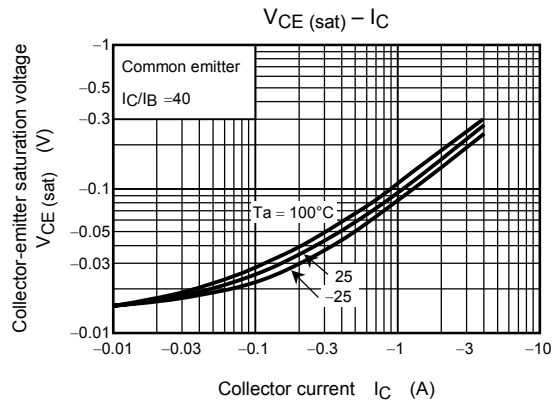
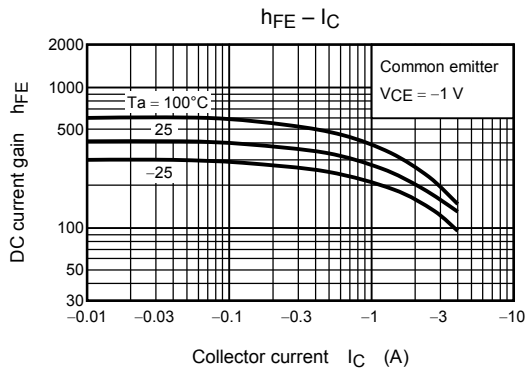
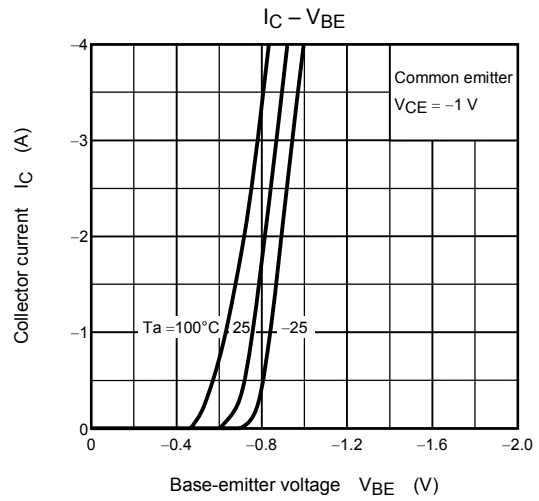
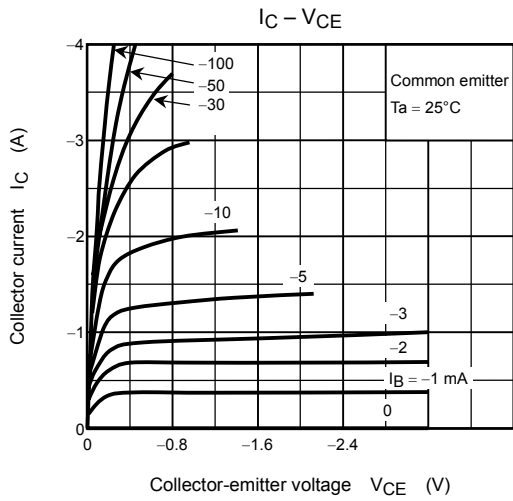
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = -20\text{ V}, I_E = 0$	—	—	-100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = -6\text{ V}, I_C = 0$	—	—	-100	nA
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -10\text{ mA}, I_B = 0$	-10	—	—	V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -1\text{ mA}, I_C = 0$	-6	—	—	V
DC current gain	$h_{FE(1)}$ (Note 3)	$V_{CE} = -1\text{ V}, I_C = -0.5\text{ A}$	140	—	600	
	$h_{FE(2)}$	$V_{CE} = -1\text{ V}, I_C = -4\text{ A}$	60	120	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -2\text{ A}, I_B = -50\text{ mA}$	—	-0.2	-0.5	V
Base-emitter voltage	V_{BE}	$V_{CE} = -1\text{ V}, I_C = -2\text{ A}$	—	-0.83	-1.5	V
Transition frequency	f_T	$V_{CE} = -1\text{ V}, I_C = -0.5\text{ A}$	—	140	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	50	—	pF

Note 3: $h_{FE(1)}$ classification A: 140 to 280, B: 200 to 400, C: 300 to 600

Marking





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